

Figure S1. Camera picture and scanning electron microscopy (SEM) images of the produced micromechanical string resonators. Left: picture of a substrate after the final PECVD nitride etch, showing the 40 individual chips. Right: SEM image, acquired at a tilt angle of 30° , showing an overview of several strings. The scale bar corresponds to $200 \, \mu m$. The inset, acquired at a tilt angle of 46° , shows a zoom-in on the anchor point where the thin strings are attached to the Si substrate. The inset scale bar corresponds to $2 \, \mu m$.

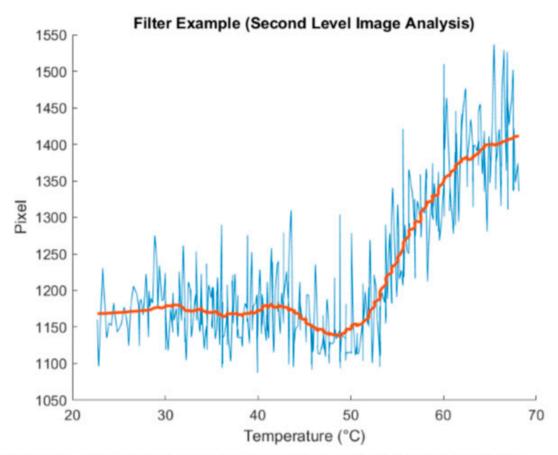


Figure S2. Measurement example of the applied filter (orange) to the raw pixel count signal (blue) obtained from the image analysis.

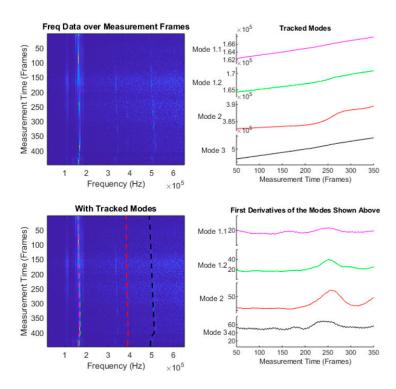


Figure S3. Left, top: Overview of the raw frequency data over the measurement frames of a single measurement. Left, bottom: Same overview with tracked mode examples. Right, top: Stacked plot of the different tracked modes. Right, bottom: First derivative of the tracked plots to highlight the different response to the slope changes during the glass transition at around frame 250 (equal to 49°C).